# BLS7G2933S-150

# LDMOS S-band radar power transistor Rev. 2 — 23 February 2011

**Product data sheet** 

#### 1. **Product profile**

#### 1.1 General description

150 W LDMOS power transistor intended for radar applications in the 2.9 GHz to 3.3 GHz range.

#### Table 1. **Typical performance**

Typical RF performance at  $T_{case}$  = 25 °C;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %;  $I_{Dq}$  = 100 mA; in a class-AB production test circuit.

Mode of operation	f	$V_{DS}$	$P_L$	$G_p$	$\eta_{\text{D}}$	t <sub>r</sub>	t <sub>f</sub>
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	2.9 to 3.3	32	150	13.5	47	20	6

#### 1.2 Features and benefits

- Typical pulsed RF performance at a frequency of 2.9 GHz to 3.3 GHz, a supply voltage of 32 V, an  $I_{Dq}$  of 100 mA, a  $t_p$  of 300  $\mu s$  with  $\delta$  of 10 %:
  - Output power = 150 W
  - ◆ Power gain = 13.5 dB
  - Efficiency = 47 %
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (2.9 GHz to 3.3 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

S-band power amplifiers for radar applications in the 2.9 GHz to 3.3 GHz frequency range



### 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		_
2	gate		ئے.
3	source	[1]	2 — 3 3 sym112

<sup>[1]</sup> Connected to flange.

### 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLS7G2933S-150	-	ceramic earless flanged cavity package; 2 leads	SOT922-1

### 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
$V_{DS}$	drain-source voltage	-	60	V
$V_{GS}$	gate-source voltage	-0.5	+13	V
I <sub>D</sub>	drain current	-	33	Α
T <sub>stg</sub>	storage temperature	-65	+150	°C
Tj	junction temperature	-	200	°C

### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{\text{th(j-mb)}} \qquad \text{transient thermal impedance from junction} \\ \text{to mounting base} \\$		$T_{case} = 85  ^{\circ}C;  P_{L} = 150  W$		
		$t_p = 100 \ \mu s; \ \delta = 10 \ \%$	0.12	K/W
		$t_p$ = 200 $\mu$ s; $\delta$ = 10 %	0.14	K/W
		$t_p$ = 300 $\mu$ s; $\delta$ = 10 %	0.16	K/W
		$t_p$ = 500 $\mu$ s; $\delta$ = 10 %	0.18	K/W
		$t_p = 100 \ \mu s; \ \delta = 20 \ \%$	0.15	K/W

### 6. Characteristics

Table 6. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.6 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 180 \text{ mA}$	1.5	1.8	2.3	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	4.2	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	29	35	-	Α
$I_{GSS}$	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	420	nΑ
g <sub>fs</sub>	forward transconductance	$V_{DS} = 10 \text{ V}; I_{D} = 9 \text{ A}$	-	12.7	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 6.3 A$	-	0.085	0.135	Ω

## 7. Application information

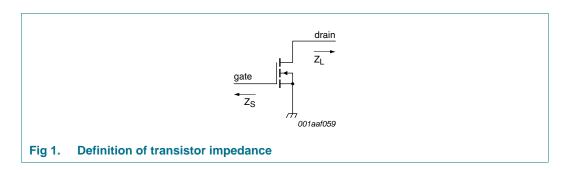
Table 7. Application information

Mode of operation: pulsed RF;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %; RF performance at  $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $T_{case}$  = 25 °C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_L$	output power		-	150	-	W
$V_{CC}$	supply voltage	P <sub>L</sub> = 150 W	-	-	32	V
$G_p$	power gain	$P_{L} = 150 \text{ W}$	11	13.5	-	dB
$RL_{in}$	input return loss	$P_{L} = 150 \text{ W}$		-10	-5.5	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	170	-	W
$\eta_{D}$	drain efficiency	$P_{L} = 150 \text{ W}$	44	47	-	%
$P_{droop(pulse)}$	pulse droop power	$P_{L} = 150 \text{ W}$	-	0	0.3	dB
t <sub>r</sub>	rise time	$P_{L} = 150 \text{ W}$	-	20	50	ns
t <sub>f</sub>	fall time	P <sub>L</sub> = 150 W	-	6	50	ns

Table 8. Typical impedance

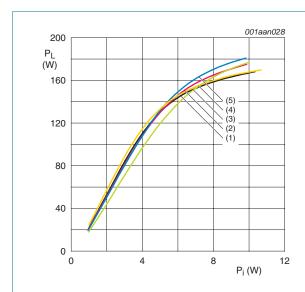
f	Z <sub>S</sub>	Z <sub>L</sub>
GHz	Ω	Ω
2.9	2.2 – j7.4	4.2 – j6.3
3.0	2.9 – j6.5	3.8 – j6.4
3.1	4.2 – j5.9	3.4 – j6.3
3.2	6.0 – j6.5	2.9 – j6.2
3.3	6.5 – j8.9	2.5 – j5.9



### 7.1 Ruggedness in class-AB operation

The BLS7G2933S-150 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $P_{L}$  = 150 W;  $t_{p}$  = 300  $\mu$ s;  $\delta$  = 10 %.

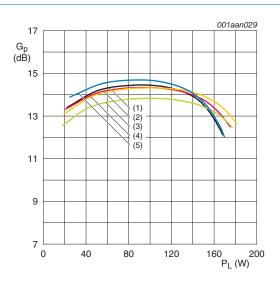
### 7.2 Graphs



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

- (1) f = 2900 MHz
- (2) f = 3000 MHz
- (3) f = 3100 MHz
- (4) f = 3200 MHz
- (5) f = 3300 MHz

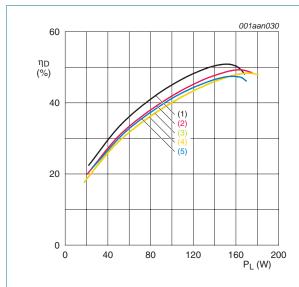
Fig 2. Load power as a function of input power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 100 \text{ mA}; t_p = 300 \text{ } \mu\text{s}; \delta = 10 \text{ } \%.$ 

- (1) f = 2900 MHz
- (2) f = 3000 MHz
- (3) f = 3100 MHz
- (4) f = 3200 MHz
- (5) f = 3300 MHz

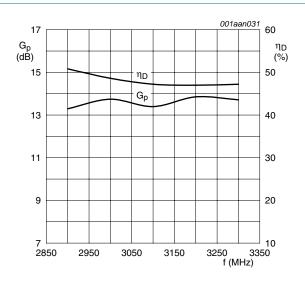
Fig 3. Power gain as a function of load power; typical values



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu s; \, \delta$  = 10 %.

- (1) f = 2900 MHz
- (2) f = 3000 MHz
- (3) f = 3100 MHz
- (4) f = 3200 MHz
- (5) f = 3300 MHz

Fig 4. Drain efficiency as a function of load power; typical values



 $V_{DS}$  = 32 V;  $P_L$  = 150 W;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %.

Fig 5. Power gain and drain efficiency as function of frequency; typical values

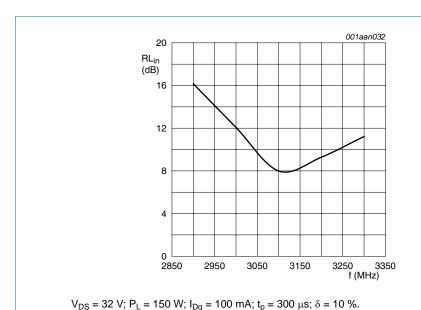
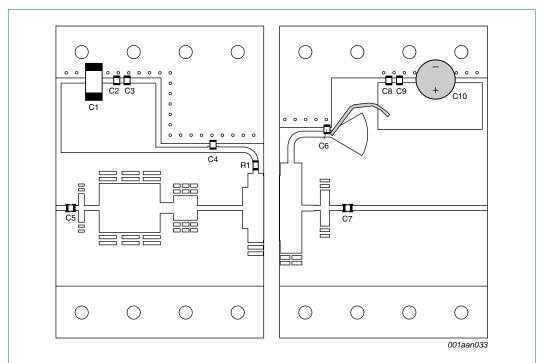


Fig 6. Input return loss as a function of frequency; typical values

### 8. Test information



Striplines are on a double copper-clad Duroid 6006 Printed-Circuit Board (PCB) with  $\epsilon_{\text{r}}$  = 6.15 and thickness = 0.64 mm.

See Table 9 for list of components.

Fig 7. Component layout for application circuit

Table 9. List of components See Figure 7.

<u>ga</u> .			
Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	10 $\mu F$ ; 20 $V$	
C2, C8	multilayer ceramic chip capacitor	1 nF	ATC 700A or equivalent
C3, C9	multilayer ceramic chip capacitor	100 pF	ATC 100A or equivalent
C4, C5, C6, C7	multilayer ceramic chip capacitor	10 pF	ATC 100A or equivalent
C10	electrolytic capacitor	68 μF; 63 V	
R1	SMD resistor	10 Ω	SMD 0603

### 9. Package outline

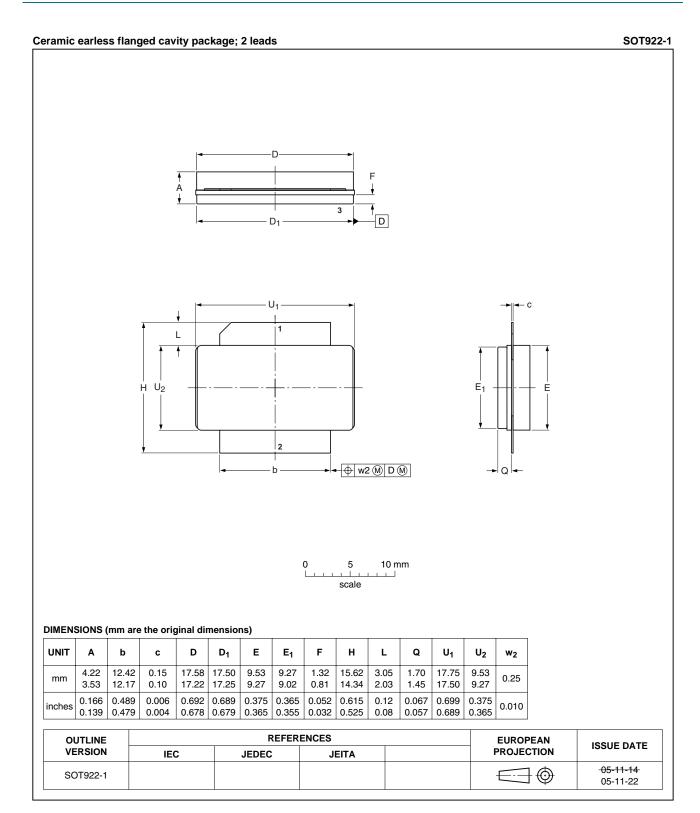


Fig 8. Package outline SOT922-1

### 10. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### 11. Abbreviations

Table 10. Abbreviations

Acronym	Description	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
RF	Radio Frequency	
S-band	Short wave Band	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	

### 12. Revision history

Table 11. Revision history

Release date	Data sheet status	Change notice	Supersedes	
20110223	Product data sheet	-	BLS7G2933S-150 v.1	
Modifications:  • The status of this data sheet has been changed to Product data sheet				
<ul> <li><u>Table 7 on page 3</u>: Maximum value of RL<sub>in</sub> has been changed</li> </ul>				
20101112	Objective data sheet	-	-	
	20110223  • The status of the Table 7 on p	20110223 Product data sheet  The status of this data sheet has been  Table 7 on page 3: Maximum value of	Product data sheet     The status of this data sheet has been changed to Product d     Table 7 on page 3: Maximum value of RL <sub>in</sub> has been change	

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#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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